

Phase Control Thyristors (Hockey PUK Version), 790 A


TO-200AC (B-PUK)
FEATURES

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case TO-200AC (B-PUK)
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912


**RoHS
COMPLIANT**
TYPICAL APPLICATIONS

- DC motor control
- Controlled DC power supplies
- AC controllers

PRODUCT SUMMARY

| | |
|-------------------|------------------------|
| Package | TO-200AC (B-PUK) |
| Diode variation | Single SCR |
| $I_{T(AV)}$ | 790 A |
| V_{DRM}/V_{RRM} | 2000 V, 2200 V, 2400 V |
| V_{TM} | 2.07 V |
| I_{GT} | 100 mA |
| T_J | -40 °C to 125 °C |

MAJOR RATINGS AND CHARACTERISTICS

| PARAMETER | TEST CONDITIONS | VALUES | UNITS |
|-------------------|-----------------|--------------|-------------------|
| $I_{T(AV)}$ | | 790 | A |
| | T_{hs} | 55 | °C |
| $I_{T(RMS)}$ | | 1557 | A |
| | T_{hs} | 25 | °C |
| I_{TSM} | 50 Hz | 10 100 | A |
| | 60 Hz | 10 700 | |
| I^2t | 50 Hz | 510 | kA ² s |
| | 60 Hz | 475 | |
| V_{DRM}/V_{RRM} | | 2000 to 2400 | V |
| t_q | Typical | 200 | µs |
| T_J | | -40 to 125 | °C |

ELECTRICAL SPECIFICATIONS
VOLTAGE RATINGS

| TYPE NUMBER | VOLTAGE CODE | V_{DRM}/V_{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V | V_{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V | I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA |
|--------------|--------------|--|--|--|
| VS-ST650C..L | 20 | 2000 | 2100 | 80 |
| | 22 | 2200 | 2300 | |
| | 24 | 2400 | 2500 | |



| ABSOLUTE MAXIMUM RATINGS | | | | | |
|--|---------------|--|---------------------------|-----------|--------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS |
| Maximum average on-state current at heatsink temperature | $I_{T(AV)}$ | 180° conduction, half sine wave Double side (single side) cooled | | 790 (324) | A |
| | | | | 55 (85) | °C |
| Maximum RMS on-state current | $I_{T(RMS)}$ | DC at 25 °C heatsink temperature double side cooled | | 1857 | |
| Maximum peak, one-cycle non-repetitive surge current | I_{TSM} | t = 10 ms | No voltage reapplied | 10 100 | A |
| | | t = 8.3 ms | | 10 700 | |
| | | t = 10 ms | 100 % V_{RRM} reapplied | 8600 | |
| | | t = 8.3 ms | | 9150 | |
| Maximum I^2t for fusing | I^2t | t = 10 ms | No voltage reapplied | 510 | kA ² s |
| | | t = 8.3 ms | | 475 | |
| | | t = 10 ms | 100 % V_{RRM} reapplied | 370 | |
| | | t = 8.3 ms | | 347 | |
| Maximum $I^2\sqrt{t}$ for fusing | $I^2\sqrt{t}$ | t = 0.1 to 10 ms, no voltage reapplied | | 5100 | kA ² /s |
| Low level value of threshold voltage | $V_{T(TO)1}$ | $(16.7 \% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J$ maximum | | 1.04 | V |
| High level value of threshold voltage | $V_{T(TO)2}$ | $(I > \pi \times I_{T(AV)})$, $T_J = T_J$ maximum | | 1.13 | |
| Low level value of on-state slope resistance | r_{t1} | $(16.7 \% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J$ maximum | | 0.61 | mΩ |
| High level value of on-state slope resistance | r_{t2} | $(I > \pi \times I_{T(AV)})$, $T_J = T_J$ maximum | | 0.35 | |
| Maximum on-state voltage | V_{TM} | $I_{pk} = 1700$ A, $T_J = T_J$ maximum, $t_p = 10$ ms sine pulse | | 2.07 | V |
| Maximum holding current | I_H | $T_J = 25$ °C, anode supply 12 V resistive load | | 600 | mA |
| Typical latching current | I_L | | | 1000 | |

| SWITCHING | | | | | |
|--|---------|--|--|--------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS |
| Maximum non-repetitive rate of rise of turned-on current | di/dt | Gate drive 20 V, 20 Ω, $t_r \leq 1$ μs $T_J = T_J$ maximum, anode voltage ≤ 80 % V_{DRM} | | 1000 | A/μs |
| Typical delay time | t_d | Gate current 1 A, $dI_g/dt = 1$ A/μs $V_d = 0.67$ % V_{DRM} , $T_J = 25$ °C | | 1.0 | μs |
| Maximum turn-off time | t_q | $I_{TM} = 750$ A, $T_J = T_J$ maximum, $dI/dt = 60$ A/μs $V_R = 50$, $dV/dt = 20$ V/μs, Gate 0 V 100 Ω, $t_p = 500$ μs | | 200 | |

| BLOCKING | | | | | |
|--|--------------------------|--|--|--------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS |
| Maximum critical rate of rise of off-state voltage | dV/dt | $T_J = T_J$ maximum linear to 80 % rated V_{DRM} | | 500 | V/μs |
| Maximum peak reverse and off-state leakage current | I_{RRM} , I_{DRM} | $T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied | | 80 | mA |



| TRIGGERING | | | | | |
|-------------------------------------|-------------|--|--------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | | UNITS |
| | | | typ. | max. | |
| Maximum peak gate power | P_{GM} | $T_J = T_J$ maximum, $t_p \leq 5$ ms | 10.0 | | W |
| Maximum average gate power | $P_{G(AV)}$ | $T_J = T_J$ maximum, $f = 50$ Hz, $d\% = 50$ | 2.0 | | |
| Maximum peak positive gate current | I_{GM} | $T_J = T_J$ maximum, $t_p \leq 5$ ms | 3.0 | | A |
| Maximum peak positive gate voltage | $+V_{GM}$ | | 20 | | |
| Maximum peak negative gate voltage | $-V_{GM}$ | | 5.0 | | |
| DC gate current required to trigger | I_{GT} | $T_J = -40$ °C | 200 | - | mA |
| | | $T_J = 25$ °C | 100 | 200 | |
| | | $T_J = 125$ °C | 50 | - | |
| DC gate voltage required to trigger | V_{GT} | $T_J = -40$ °C | 2.5 | - | V |
| | | $T_J = 25$ °C | 1.8 | 3.0 | |
| | | $T_J = 125$ °C | 1.1 | - | |
| DC gate current not to trigger | I_{GD} | $T_J = T_J$ maximum | 10 | | mA |
| DC gate voltage not to trigger | V_{GD} | | 0.25 | | |

| THERMAL AND MECHANICAL SPECIFICATIONS | | | | |
|--|--------------|---|------------------|-----------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum operating temperature range | T_J | | -40 to 125 | °C |
| Maximum storage temperature range | T_{Stg} | | -40 to 150 | |
| Maximum thermal resistance, junction to heatsink | R_{thJ-hs} | DC operation single side cooled | 0.073 | K/W |
| | | DC operation double side cooled | 0.031 | |
| Maximum thermal resistance, case to heatsink | R_{thC-hs} | DC operation single side cooled | 0.011 | |
| | | DC operation double side cooled | 0.006 | |
| Mounting force, ± 10 % | | | 14 700 (1500) | N (kg) |
| Approximate weight | | | 255 | g |
| Case style | | See dimensions - link at the end of datasheet | TO-200AC (B-PUK) | |

| ΔR_{thJ-hs} CONDUCTION | | | | | | |
|--------------------------------|-----------------------|-------------|------------------------|-------------|---------------------|-------|
| CONDUCTION ANGLE | SINUSOIDAL CONDUCTION | | RECTANGULAR CONDUCTION | | TEST CONDITIONS | UNITS |
| | Single Side | Double Side | Single Side | Double Side | | |
| 180° | 0.009 | 0.009 | 0.006 | 0.006 | $T_J = T_J$ maximum | K/W |
| 120° | 0.011 | 0.011 | 0.011 | 0.011 | | |
| 90° | 0.014 | 0.014 | 0.015 | 0.015 | | |
| 60° | 0.020 | 0.020 | 0.021 | 0.021 | | |
| 30° | 0.036 | 0.036 | 0.036 | 0.036 | | |

Note

- The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

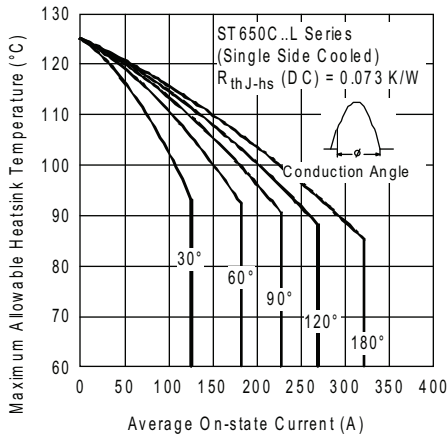


Fig. 1 - Current Ratings Characteristics

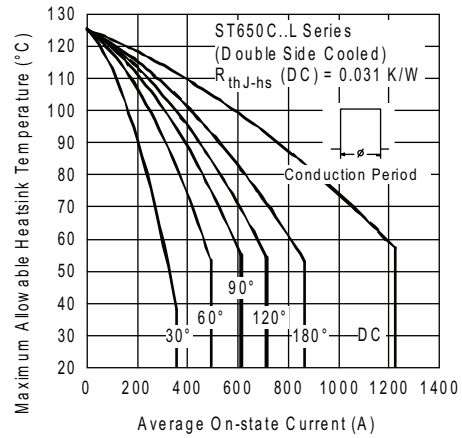


Fig. 4 - Current Ratings Characteristics

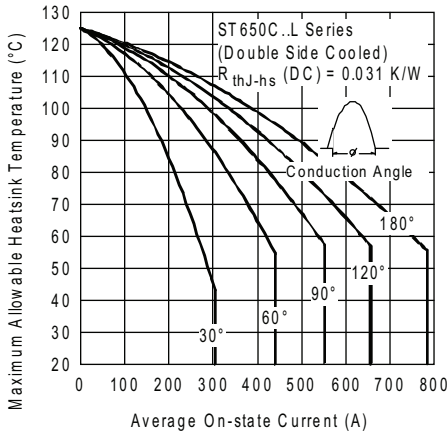


Fig. 2 - Current Ratings Characteristics



Fig. 5 - On-State Power Loss Characteristics

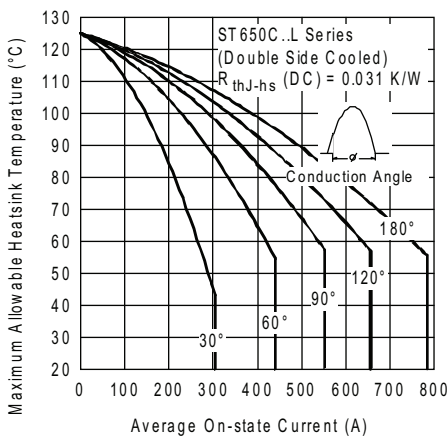


Fig. 3 - Current Ratings Characteristics



Fig. 6 - On-State Power Loss Characteristics

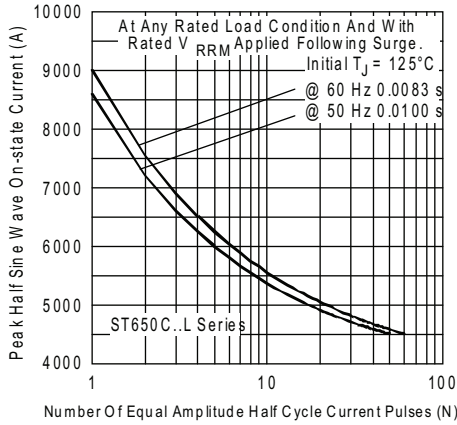


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

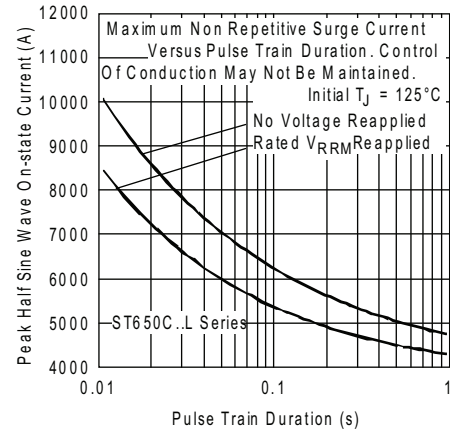


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

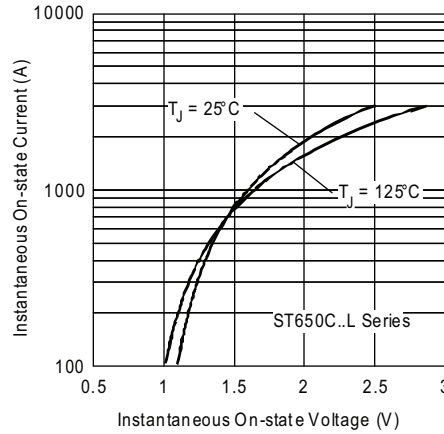


Fig. 9 - On-State Voltage Drop Characteristics

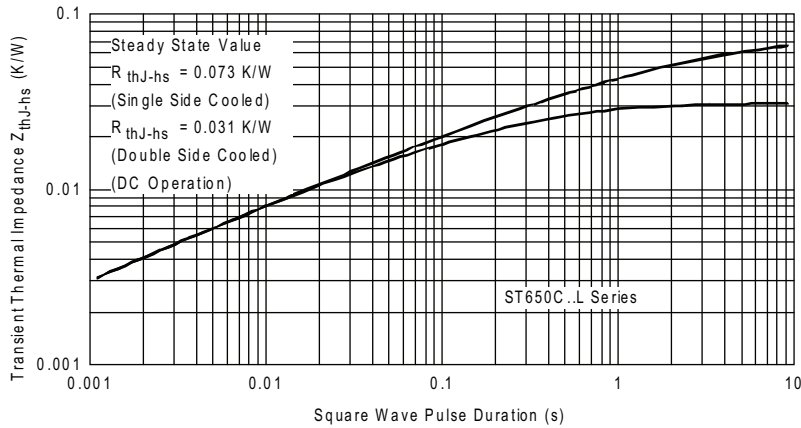


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics



Fig. 11 - Gate Characteristics

ORDERING INFORMATION TABLE

| | | | | | | | | | |
|-------------|------------|-----------|--|----------|----------|--|----------|----------|---|
| Device code | VS- | ST | 65 | 0 | C | 24 | L | 1 | - |
| | ① | ② | ③ | ④ | ⑤ | ⑥ | ⑦ | ⑧ | ⑨ |
| | 1 | - | Vishay Semiconductors product | 2 | - | Thyristor | 3 | - | Essential part number |
| | 4 | - | 0 = Converter grade | 5 | - | C = Ceramic PUK | 6 | - | Voltage code x 100 = V_{RRM} (see Voltage Ratings table) |
| | 7 | - | L = PUK case TO-200AC (B-PUK) | 8 | - | 0 = Eyelet terminals (gate and auxiliary cathode unsoldered leads) | 1 | - | Fast-on terminals (gate and auxiliary cathode unsoldered leads) |
| | 2 | - | Eyelet terminals (gate and auxiliary cathode soldered leads) | 3 | - | Fast-on terminals (gate and auxiliary cathode soldered leads) | 9 | - | Critical dv/dt: • None = 500 V/μs (standard selection) |
| | L | - | L = 1000 V/μs (special selection) | | | | | | |

LINKS TO RELATED DOCUMENTS

| | |
|------------|--|
| Dimensions | www.vishay.com/doc?95076 |
|------------|--|

TO-200AC (B-PUK)

DIMENSIONS in millimeters (inches)

Creepage distance: 36.33 (1.430) minimum
 Strike distance: 17.43 (0.686) minimum



Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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